

DESCRIPTION

The GLF1411 is an ultra-efficient dual channel load switch with slew rate control. The devices feature the ultra-efficient I_QSmart™ technology that supports some of the lowest R_{ON}, quiescent currents (I_Q), and shutdown currents (I_{SD}) in an input voltage range from 1.5 V to 5.5 V.

The integrated slew rate control can also enhance system reliability by mitigating bus voltage swings during switching events. Where uncontrolled switches can generate high inrush currents that result in voltage droop and/or bus reset events, the GLF1411 slew rate control specifically limits inrush current during turn-on to minimize voltage droop.

Each channel runs independently controlled by separate EN control pin. Both devices feature an integrated output discharge switch when they are turned off to discharge output capacitors quickly.

APPLICATIONS

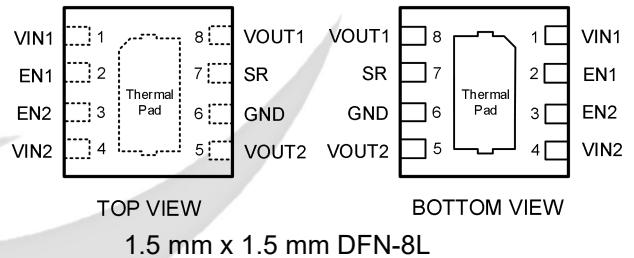
- Smart Mobile Devices
- IoT Devices
- Low Power Subsystems

FEATURES

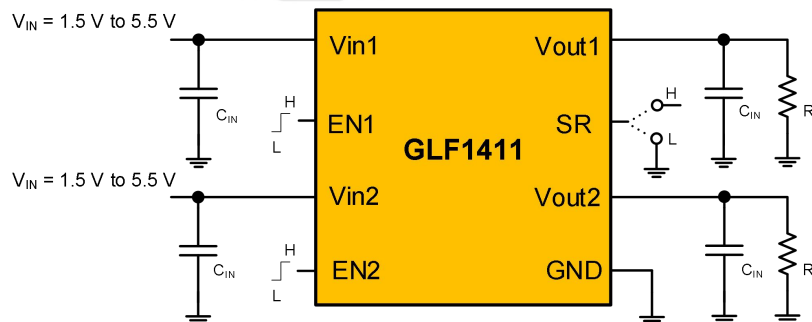
Per Channel

- Supply Voltage Range: 1.5 V to 5.5 V
- Low R_{ON}:
 - 180 mΩ Typ @ 5.5 V_{IN}
 - 220 mΩ Typ @ 3.3 V_{IN}
 - 265 mΩ Typ @ 2.5 V_{IN}
- I_{OUT} Max: 1 A Continuous Output Current
- Ultra-Low Quiescent Current, I_Q
 - 10 nA Typ. at 5.5 V_{IN}
 - 5 nA Typ. at 3.3 V_{IN}
 - 4 nA Typ. at 2.5 V_{IN}
- Ultra-Low Stand-by Current, I_{SD}
 - 32 nA Typ. at 5.5 V_{IN}
 - 4 nA Typ. at 3.3 V_{IN}
 - 3 nA Typ. at 2.5 V_{IN}
- Slew Rate Control Pin of Output Rise Time
- Output Discharge Switch When Disabled

PACKAGE



APPLICATION DIAGRAM



ALTERNATE DEVICE OPTIONS

Part Number	Top Mark	R _{ON} (Typ) at 5.5 V	TRCB	Output Discharge	V _{OUT} Rise Time t _r (Typ) at 3.3 V	EN Activity	Availability
GLF1411-D1G7	DR	180 mΩ	NA	95 Ω	380 μs at SR= High 60 μs at SR= GND	High	Released
GLF1421-D1G7	DS		Yes				In Dev.

FUNCTIONAL BLOCK DIAGRAM

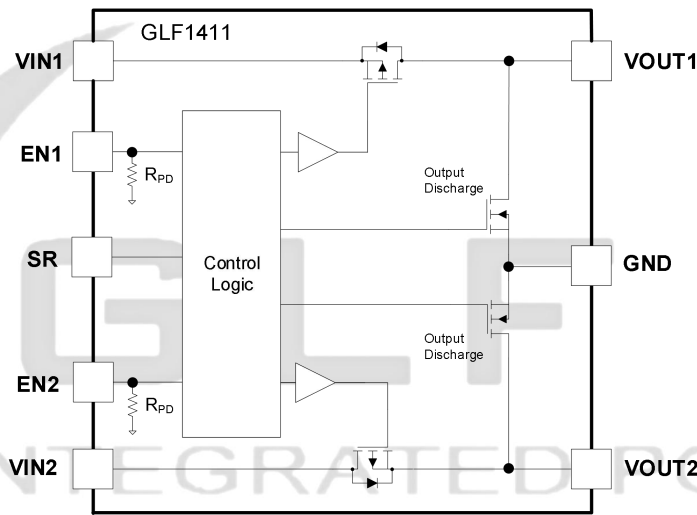


Figure 1. Functional Block Diagram

PIN CONFIGURATION

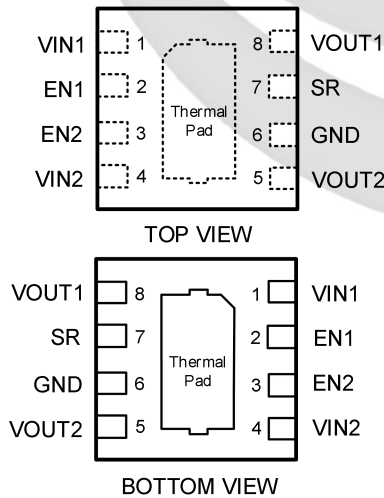


Figure 2. 1.5 mm x 1.5 mm DFN-8L

PIN DEFINITION

Pin	Name	Description
1	VIN1	Switch 1 input.
2	EN1	Active high signal to enable the switch 1
3	EN2	Active high signal to enable the switch 2
4	VIN2	Switch 2 input.
5	VOUT2	Switch 2 output
6	GND	Ground
7	SR	Slew rate control of V _{OUT1} and V _{OUT2} . SR = High (Slow) SR = GND (Fast)
8	VOUT1	Switch 1 output
	Thermal pad	Tie to GND

ABSOLUTE MAXIMUM RATINGS

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Min.	Max.	Unit
V_{IN} , V_{OUT} , EN, SR	Each Pin to GND	-0.3	6	V
I_{OUT}	Maximum Continuous Switch Current	$T_A = 25\text{ }^\circ\text{C}$	1	A
		$T_A = 85\text{ }^\circ\text{C}$	0.8	A
T_J	Maximum Junction Temperature		150	$^\circ\text{C}$
T_{STG}	Storage Junction Temperature	-65	150	$^\circ\text{C}$
T_A	Ambient Operating Temperature Range	-40	85	$^\circ\text{C}$
θ_{JA}	Thermal Resistance, Junction to Ambient		190	$^\circ\text{C}/\text{W}$
θ_{JC_Top}	Thermal Resistance, Junction to Case		95	$^\circ\text{C}/\text{W}$
ESD	Electrostatic Discharge Capability	Human Body Model, JESD22-A114	5	kV
		Charged Device Model, JESD22-C101	2	

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min.	Max.	Unit
V_{IN}	Supply Voltage	1.5	5.5	V
T_A	Ambient Operating Temperature	-40	+85	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS (Per Channel)

 Values are at $V_{IN} = 3.3\text{ V}$ and $T_A = 25\text{ °C}$ unless otherwise noted.

Symbol	Parameter	Conditions	Min	Typ	Max	Units
Basic Operation						
I_Q	Quiescent Current ⁽¹⁾ Each Channel	$EN = V_{IN}, I_{OUT} = 0\text{ mA}, V_{IN} = 1.5\text{ V}$		3		nA
		$EN = V_{IN}, I_{OUT} = 0\text{ mA}, V_{IN} = 1.8\text{ V}$		3.5		
		$EN = V_{IN}, I_{OUT} = 0\text{ mA}, V_{IN} = 2.5\text{ V}$		4		
		$EN = V_{IN}, I_{OUT} = 0\text{ mA}, V_{IN} = 3.3\text{ V}$		5	20	
		$EN = V_{IN}, I_{OUT} = 0\text{ mA}, V_{IN} = 5.5\text{ V}$		10		
		$EN = V_{IN}, I_{OUT} = 0\text{ mA}, V_{IN} = 5.5\text{ V}, T_A = 85\text{ °C}^{(4)}$		19		
I_{SD}	Shut Down Current Each Channel	$EN = 0\text{ V}, I_{OUT} = 0\text{ mA}, V_{IN} = 1.5\text{ V}$		2		nA
		$EN = 0\text{ V}, I_{OUT} = 0\text{ mA}, V_{IN} = 1.8\text{ V}$		2		
		$EN = 0\text{ V}, I_{OUT} = 0\text{ mA}, V_{IN} = 2.5\text{ V}$		3		
		$EN = 0\text{ V}, I_{OUT} = 0\text{ mA}, V_{IN} = 3.3\text{ V}$		4	50	
		$EN = 0\text{ V}, I_{OUT} = 0\text{ mA}, V_{IN} = 5.5\text{ V}$		32		
		$EN = 0\text{ V}, I_{OUT} = 0\text{ mA}, V_{IN} = 5.5\text{ V}, T_A = 85\text{ °C}^{(4)}$		100		
R_{ON}	On-Resistance	$V_{IN} = 5.5\text{ V}, I_{OUT} = 500\text{ mA}$	$T_A = 25\text{ °C}$	180	240	mΩ
			$T_A = 85\text{ °C}^{(4)}$	220		
		$V_{IN} = 3.3\text{ V}, I_{OUT} = 500\text{ mA}$	$T_A = 25\text{ °C}$	220	300	
		$V_{IN} = 2.5\text{ V}, I_{OUT} = 300\text{ mA}$	$T_A = 25\text{ °C}$	265		
		$V_{IN} = 1.8\text{ V}, I_{OUT} = 300\text{ mA}$	$T_A = 25\text{ °C}$	375		
		$V_{IN} = 1.5\text{ V}, I_{OUT} = 100\text{ mA}$	$T_A = 25\text{ °C}$	470		
R_{DSC}	Output Discharge Resistance	$EN = 0\text{ V}, I_{FORCE} = 10\text{ mA}$		95		Ω
V_{IH}	EN Input Logic High Voltage	$V_{IN} = 1.5\text{ V to } 5.5\text{ V}$	1.1			V
V_{IL}	EN Input Logic Low Voltage	$V_{IN} = 1.5\text{ V to } 5.5\text{ V}$			0.45	V
R_{EN}	EN Internal Resistance	Internal Pull-down Resistance		20		MΩ
I_{EN}	EN Current	$EN = V_{IN}$ or 0 V		0.25		μA
Switching Characteristics ⁽²⁾						
t_{dON}	Turn-On Delay ⁽⁴⁾	SR= High	$V_{IN} = 1.8\text{ V}$ $C_{OUT} = 0.1\text{ μF}, R_L = 150\text{ Ω}$	840		μs
t_R	V_{OUT} Rise Time ⁽⁴⁾			570		
t_{dOFF}	Turn-Off Delay ^{(3), (4)}			19		
t_F	V_{OUT} Fall Time ^{(3), (4)}	10				
t_{dON}	Turn-On Delay ⁽⁴⁾	SR= GND		120		
t_R	V_{OUT} Rise Time ⁽⁴⁾			70		
t_{dOFF}	Turn-Off Delay ^{(3), (4)}			20		
t_F	V_{OUT} Fall Time ^{(3), (4)}			10		
t_{dON}	Turn-On Delay			SR= High	380	
t_R	V_{OUT} Rise Time	390				
t_{dOFF}	Turn-Off Delay ^{(3), (4)}	20				
t_F	V_{OUT} Fall Time ^{(3), (4)}	12				
t_{dON}	Turn-On Delay	SR= GND	60			
t_R	V_{OUT} Rise Time		45			
t_{dOFF}	Turn-Off Delay ^{(3), (4)}		20			

t_F	V_{OUT} Fall Time ^{(3), (4)}	SR= High	$V_{IN} = 5.0 V$ $C_{OUT}=0.1 \mu F, R_L=150 \Omega$	12	μs
t_{dON}	Turn-On Delay ⁽⁴⁾			230	
t_R	V_{OUT} Rise Time ⁽⁴⁾			320	
t_{dOFF}	Turn-Off Delay ^{(3), (4)}			20	
t_F	V_{OUT} Fall Time ^{(3), (4)}			12	
t_{dON}	Turn-On Delay ⁽⁴⁾	SR= GND	$V_{IN} = 5.0 V$ $C_{OUT}=0.1 \mu F, R_L=150 \Omega$	43	μs
t_R	V_{OUT} Rise Time ⁽⁴⁾			30	
t_{dOFF}	Turn-Off Delay ^{(3), (4)}			20	
t_F	V_{OUT} Fall Time ^{(3), (4)}			12	

- Notes:
1. I_Q does not include Enable pull down current through the pull-down resistor R_{PD} .
 2. $t_{ON} = t_{dON} + t_R$, $t_{OFF} = t_{dOFF} + t_F$
 3. Output discharge path is enabled during off.
 4. By design; characterized, not production tested.

TIMING DIAGRAM

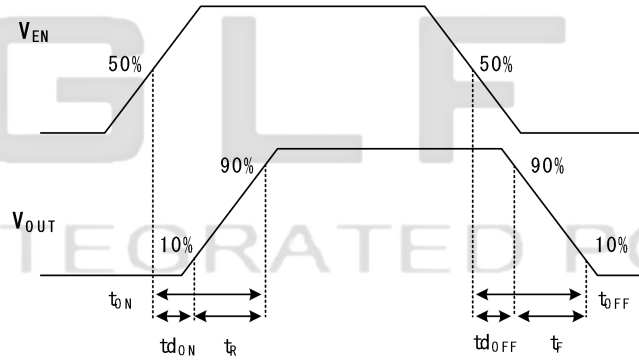


Figure 3. Timing Diagram

TYPICAL PERFORMANCE CHARACTERISTICS (Per Channel)

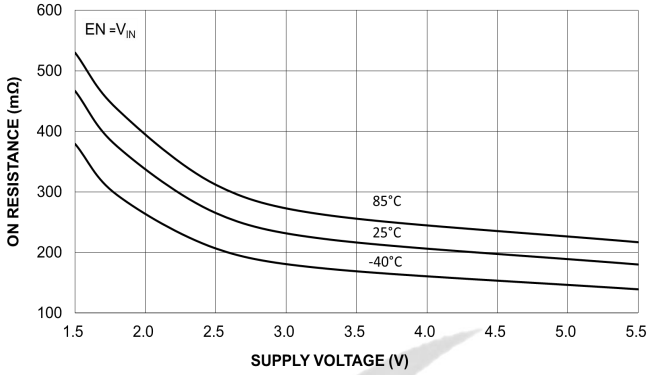


Figure 4. On-Resistance vs. Supply Voltage

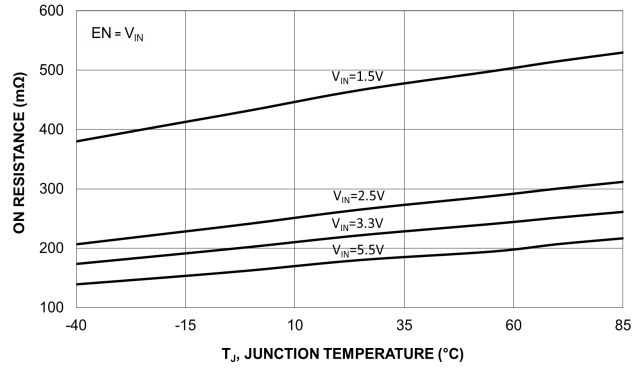


Figure 5. On-Resistance vs. Temperature

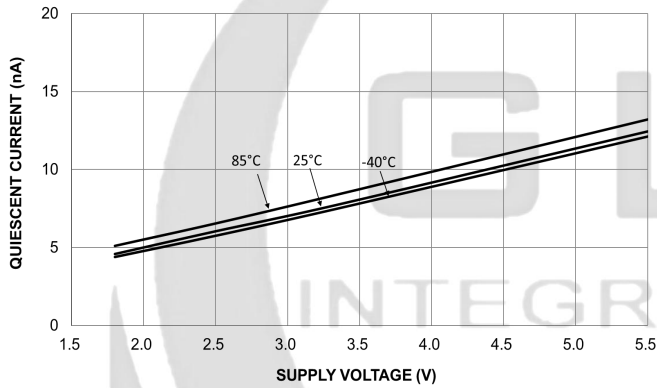


Figure 6. Quiescent Current vs. Supply Voltage

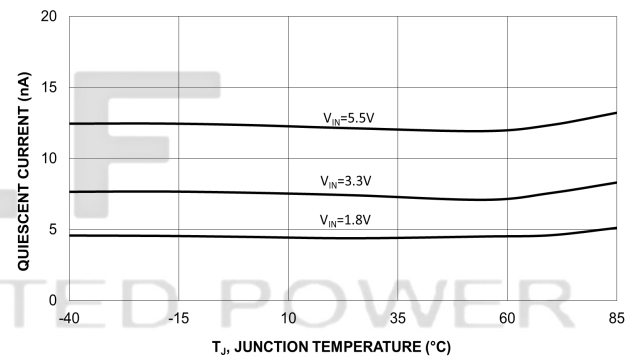


Figure 7. Quiescent Current vs. Temperature

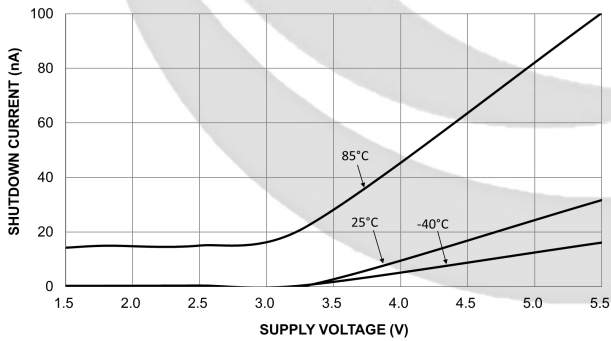


Figure 8. Shutdown Current vs. Supply Voltage

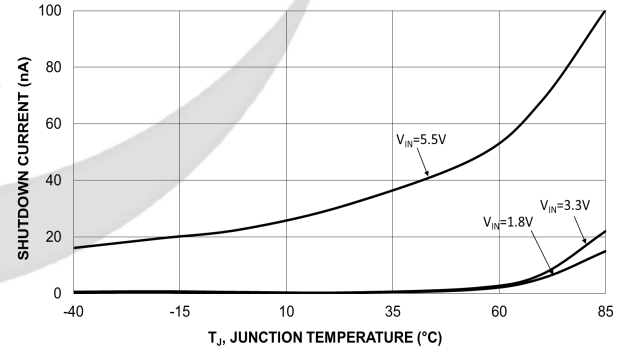


Figure 9. Shutdown Current vs. Temperature

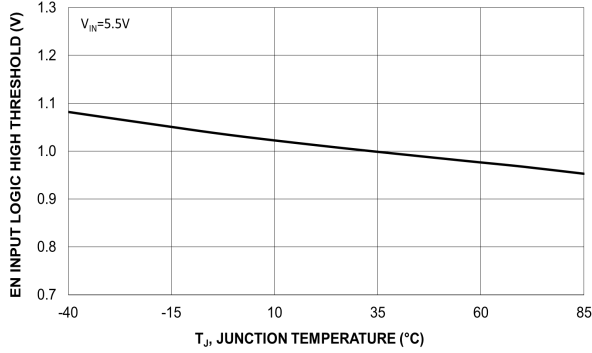


Figure 10. EN Input Logic High Threshold vs. Temperature

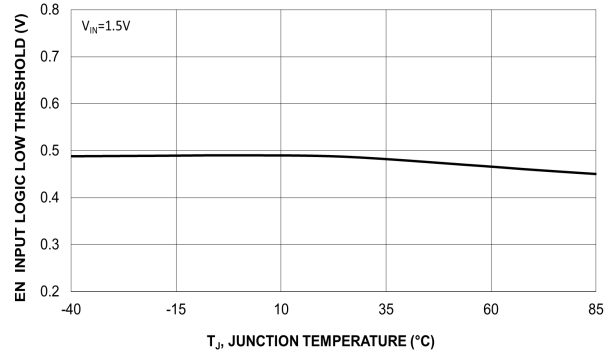


Figure 11. EN Input Logic Low Threshold vs. Temperature

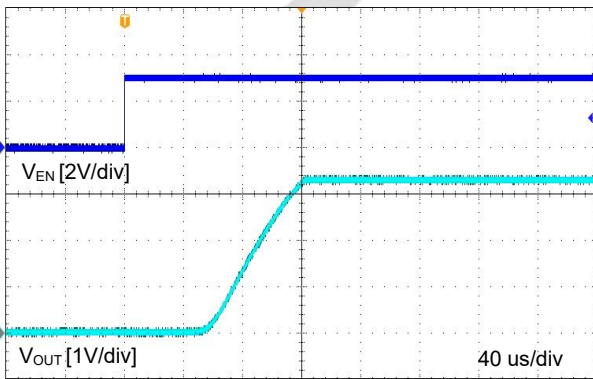


Figure 12. Turn-On Response

$V_{IN}=3.3\text{ V}$, $SR=GND$, $C_{IN}=0.1\ \mu\text{F}$, $C_{OUT}=0.1\ \mu\text{F}$, $R_L=150\ \Omega$

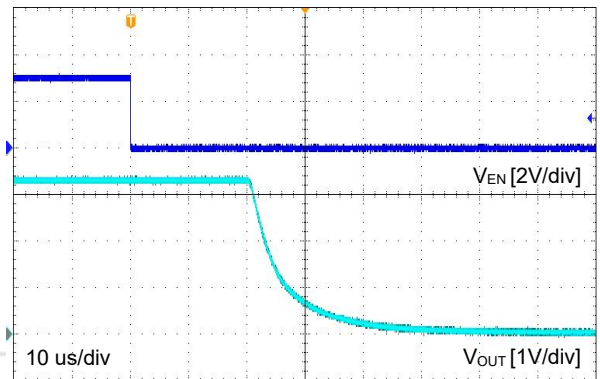


Figure 13. Turn-Off Response

$V_{IN}=3.3\text{ V}$, $SR=GND$, $C_{IN}=0.1\ \mu\text{F}$, $C_{OUT}=0.1\ \mu\text{F}$, $R_L=150\ \Omega$

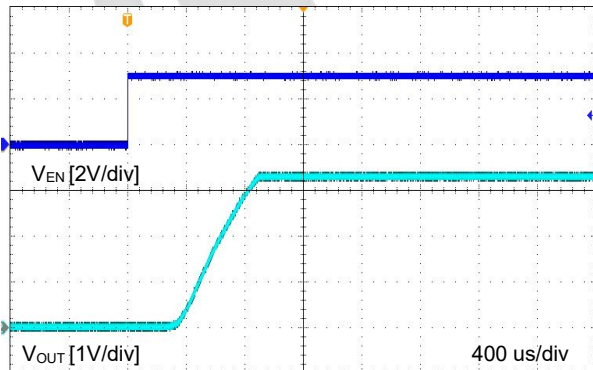


Figure 14. Turn-On Response

$V_{IN}=3.3\text{ V}$, $SR=High$, $C_{IN}=0.1\ \mu\text{F}$, $C_{OUT}=0.1\ \mu\text{F}$, $R_L=150\ \Omega$

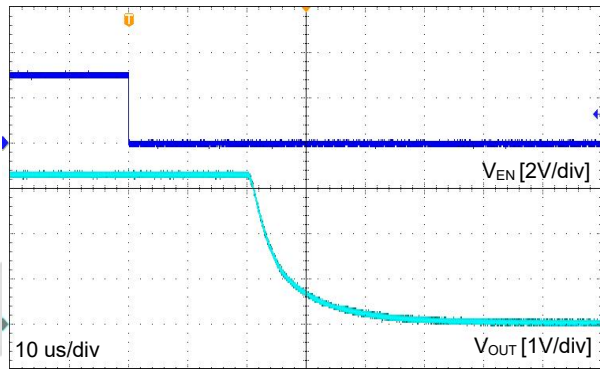


Figure 15. Turn-Off Response

$V_{IN}=3.3\text{ V}$, $SR=High$, $C_{IN}=0.1\ \mu\text{F}$, $C_{OUT}=0.1\ \mu\text{F}$, $R_L=150\ \Omega$

APPLICATION INFORMATION

The GLF1411 is an integrated 800 mA, Ultra-Efficient IqSmart™ dual channel load switch devices with a fixed slew rate control to limit the inrush current during turn on. Each device is capable of operating independently over a wide input range from 1.5 V to 5.5 V with very low on-resistance to reduce conduction loss. In the off state, these devices consume very low leakage current to avoid unwanted standby current and save limited input power. The package is a 1.5 mm x 1.5 mm DFN-8L package, saving space in compact applications.

Input Capacitor

A capacitor is recommended to be placed close to the V_{IN} pin to reduce the voltage drop on the input power rail caused by transient inrush current at start-up. A higher input capacitor value can be used to further attenuate the input voltage drop.

Output Capacitor

The GLF1411 does not require an output capacitor. However, use of an output capacitor is recommended to mitigate voltage undershoot on the output pin when the switch is turning off. Undershoot can be caused by parasitic inductance from board traces or intentional load inductances. If load inductances do exist, use of an output capacitor can improve output voltage stability and system reliability. The C_{OUT} capacitor should be spaced close to the VOUT and GND pins.

EN pin

The GLF1411 can be activated by forcing EN pin high level. Note that the EN pin has an internal pull-down/ pull-up resistor to help pull the main switch to a known “off state” when no EN signal is applied from an external controller.

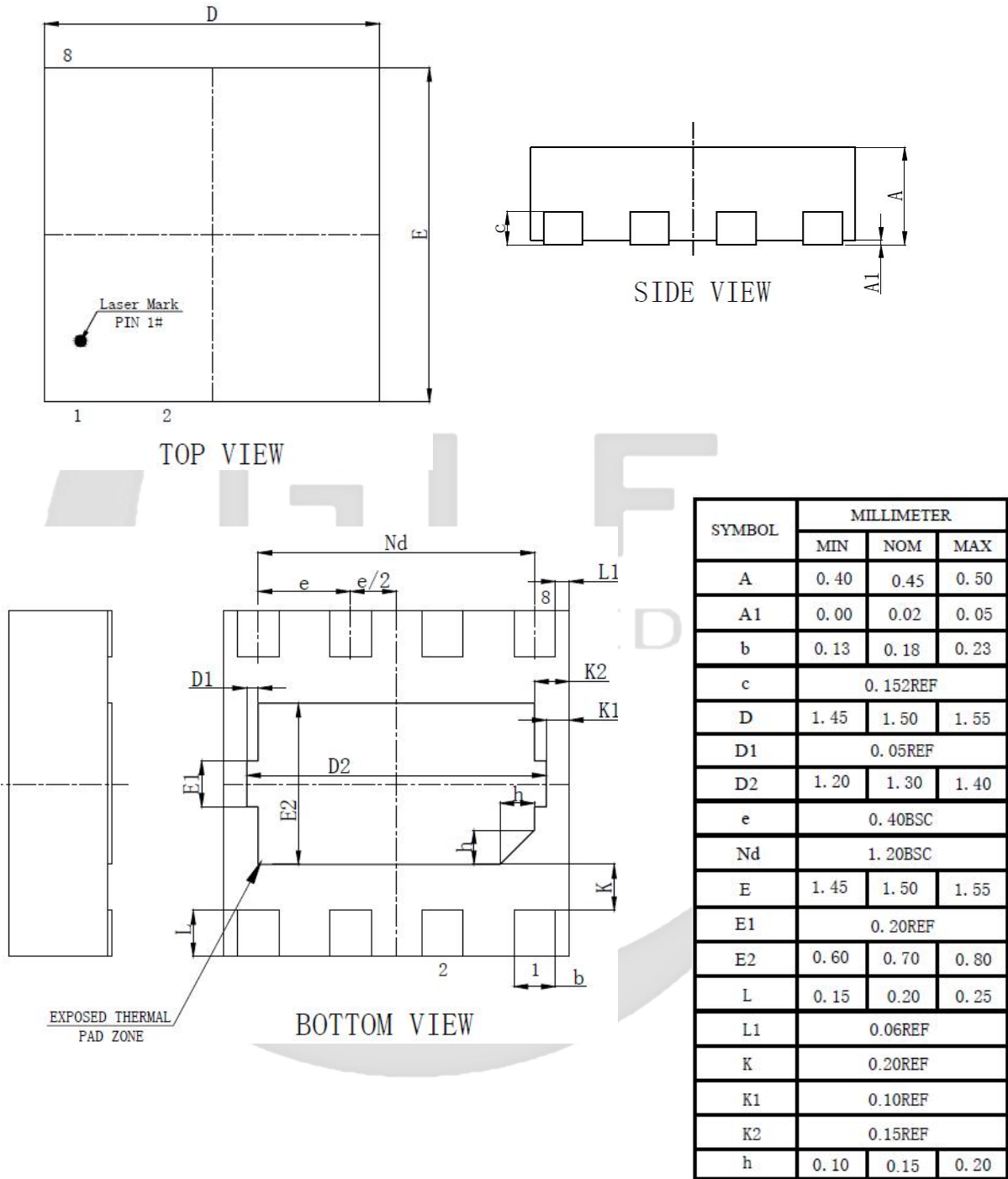
Output Discharge Function

The GLF1411 have an internal discharge N-channel FET switch on the VOUT pin. When EN signal turns the main power FET to an off state, the N-channel switch turns on to discharge an output capacitor quickly

Board Layout

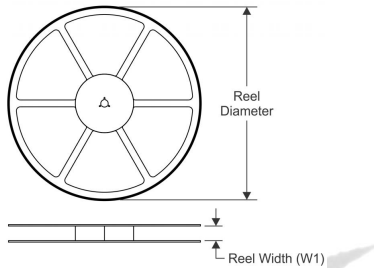
All traces should be as short as possible to minimize parasitic inductance effects. Wide traces for VIN, VOUT, and GND will help reduce signal degradation and parasitic effects during dynamic operation as well as improve the thermal performance at high load current.

PACKAGE OUTLINE

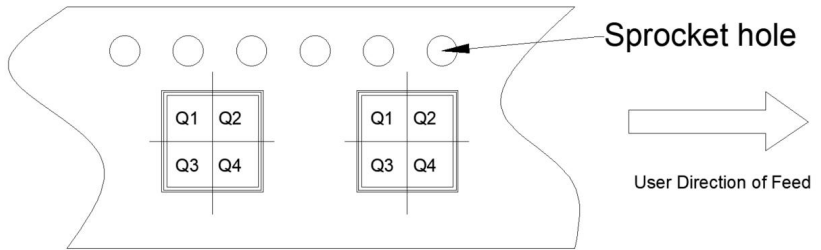


TAPE AND REEL INFORMATION

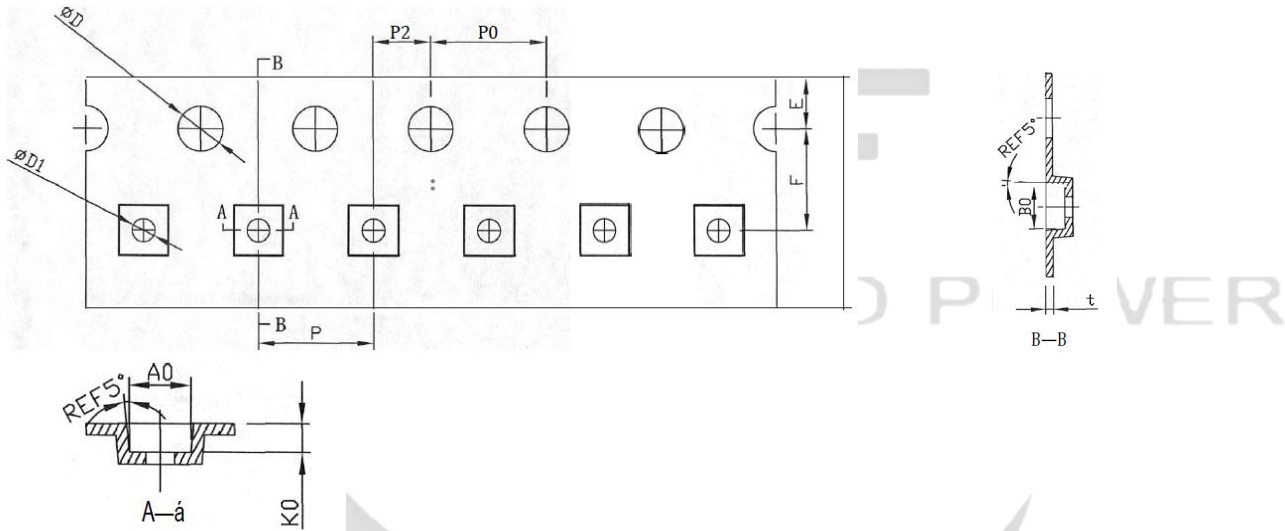
REEL DIMENSIONS



QUADRANT ASSIGNMENTS PIN 1 ORIENTATION TAPE



TAPE DIMENSIONS



Device	Package	Pins	SPQ	Reel Diameter (mm)	Reel Width W1	A0	B0	K0	P	W	Pin1
GLF1411-D1G7	DFN1.5x1.5	8	3000	178	8.6	1.7	1.7	0.76	4	8	Q1

Remark:

A0: Dimension designed to accommodate the component width

B0: Dimension designed to accommodate the component length

C0: Dimension designed to accommodate the component thickness

W: Overall width of the carrier tape

P1: Pitch between successive cavity centers

SPECIFICATION DEFINITIONS

Document Type	Meaning	Product Status
Target Specification	This is a target specification intended to support exploration and discussion of critical needs for a proposed or target device. Spec limits including typical, minimum, and maximum values are desired, or target, limits. GLF reserves the right to change limits at any time without warning or notification. A target specification in no way guarantees future production of the device in question.	Design / Development
Preliminary Specification	This is a draft version of a product specification. The specification is still under internal review and subject to change. GLF reserves the right to change the specification at any time without warning or notification. A preliminary specification in no way guarantees future production of the device in question.	Qualification
Product Specification	This document represents the anticipated production performance characteristics of the device.	Production

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